



# PSMN1R6-40YLC

N-channel 40 V 1.55 mΩ logic level MOSFET in LFPAK using NextPower technology

22 August 2012

Product data sheet

## 1. Product profile

### 1.1 General description

Logic level enhancement mode N-channel MOSFET in LFPAK package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

### 1.2 Features and benefits

- High reliability Power SO8 package, qualified to 150°C
- Optimised for 4.5V Gate drive utilising NextPower Superjunction technology
- Ultra low QG, QGD, & QOSS for high system efficiencies at low and high loads
- Ultra low Rdson and low parasitic inductance

### 1.3 Applications

- DC-to-DC converters
- Load switching
- Power OR-ing
- Server power supplies
- Sync rectifier

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$25\text{ }^{\circ}\text{C} \leq T_j \leq 150\text{ }^{\circ}\text{C}$		-	-	40	V
$I_D$	drain current	$T_{mb} = 25\text{ }^{\circ}\text{C}$ ; $V_{GS} = 10\text{ V}$ ; <a href="#">Fig. 1</a>	[1]	-	-	100	A
$P_{tot}$	total power dissipation	$T_{mb} = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 2</a>		-	-	288	W
$T_j$	junction temperature			-55	-	150	$^{\circ}\text{C}$
<b>Static characteristics</b>							
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 4.5\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 12</a>		-	1.45	1.8	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}$ ; $I_D = 25\text{ A}$ ; $T_j = 25\text{ }^{\circ}\text{C}$ ; <a href="#">Fig. 12</a>		-	1.25	1.55	$\text{m}\Omega$
<b>Dynamic characteristics</b>							
$Q_{GD}$	gate-drain charge	$V_{GS} = 4.5\text{ V}$ ; $I_D = 25\text{ A}$ ; $V_{DS} = 20\text{ V}$ ; <a href="#">Fig. 14</a>		-	15.3	-	nC

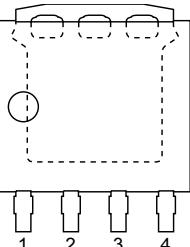
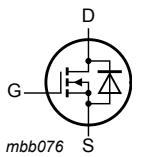
**nexperia**

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$Q_{G(\text{tot})}$	total gate charge	$V_{GS} = 4.5 \text{ V}$ ; $I_D = 25 \text{ A}$ ; $V_{DS} = 20 \text{ V}$ ; <a href="#">Fig. 14</a>		-	59	-	nC

[1] Continuous current is limited by package.

## 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		
3	S	source		
4	G	gate		
mb	D	mounting base; connected to drain	 <b>LFPAK; Power-SO8 (SOT1023)</b>	

## 3. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description	Version	
PSMN1R6-40YLC	LFPAK; Power-SO8	Plastic single-ended surface-mounted package (LFPAK); 4 leads	SOT1023	

## 4. Limiting values

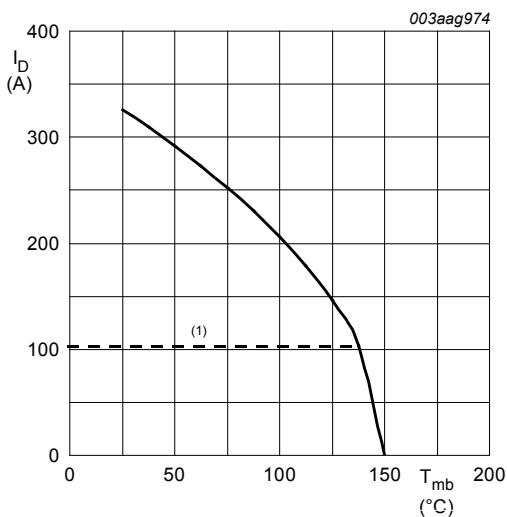
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	$25^\circ\text{C} \leq T_j \leq 150^\circ\text{C}$		-	40	V
$V_{DGR}$	drain-gate voltage	$25^\circ\text{C} \leq T_j \leq 150^\circ\text{C}$ ; $R_{GS} = 20 \text{ k}\Omega$		-	40	V
$V_{GS}$	gate-source voltage			-20	20	V
$I_D$	drain current	$V_{GS} = 10 \text{ V}$ ; $T_{mb} = 25^\circ\text{C}$ ; <a href="#">Fig. 1</a>	[1]	-	100	A
		$V_{GS} = 10 \text{ V}$ ; $T_{mb} = 100^\circ\text{C}$ ; <a href="#">Fig. 1</a>	[1]	-	100	A
$I_{DM}$	peak drain current	pulsed; $t_p \leq 10 \mu\text{s}$ ; $T_{mb} = 25^\circ\text{C}$ ; <a href="#">Fig. 4</a>		-	1304	A
$P_{\text{tot}}$	total power dissipation	$T_{mb} = 25^\circ\text{C}$ ; <a href="#">Fig. 2</a>		-	288	W
$T_{\text{stg}}$	storage temperature			-55	150	°C

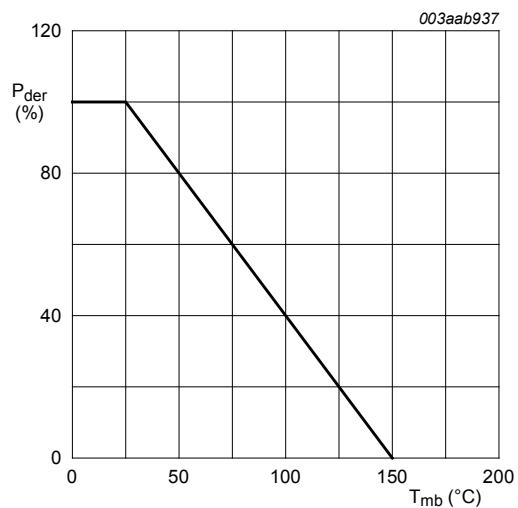
Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>j</sub>	junction temperature		-55	150	°C
T <sub>sld(M)</sub>	peak soldering temperature		-	260	°C
V <sub>ESD</sub>	electrostatic discharge voltage	MM (JEDEC JESD22-A115)	1	-	kV
<b>Source-drain diode</b>					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	100 A
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C	-	1304	A
<b>Avalanche ruggedness</b>					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	V <sub>GS</sub> = 10 V; T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = 100 A; V <sub>sup</sub> ≤ 40 V; R <sub>GS</sub> = 50 Ω; unclamped; Fig. 3	-	391	mJ

[1] Continuous current is limited by package.



**Fig. 1. Continuous drain current as a function of mounting base temperature**

$V_{GS} \geq 10 V$   
(1) Capped at 100 A due to package.



**Fig. 2. Normalized total power dissipation as a function of solder point temperature**

$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100 \%$$

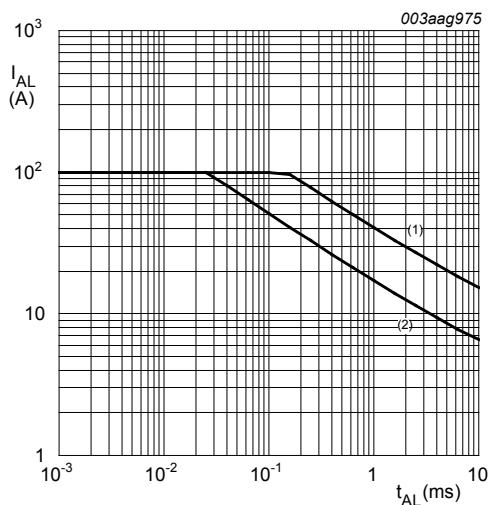


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

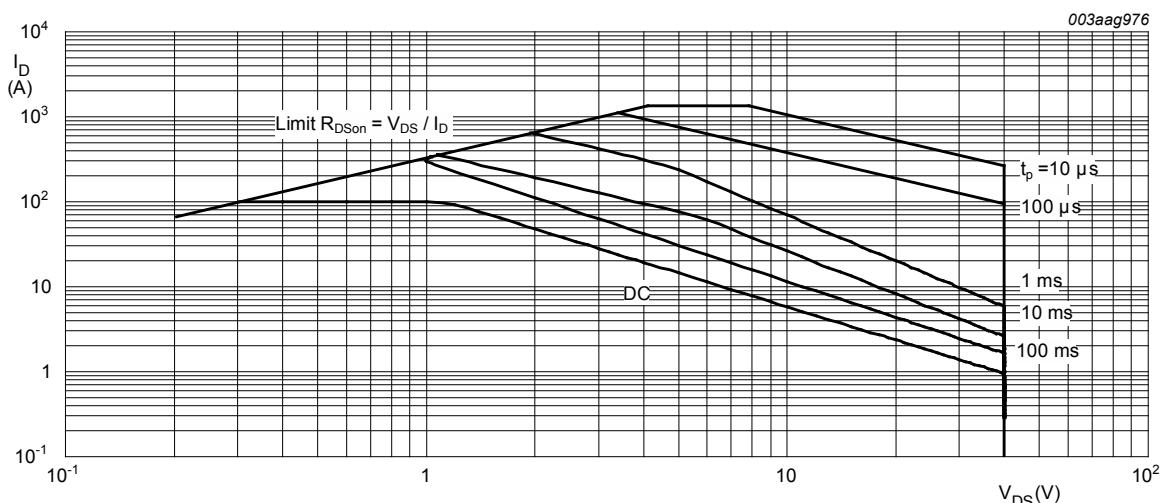
(1)  $T_j \text{ (init)} = 25^\circ\text{C}$ ; (2)  $T_j \text{ (init)} = 100^\circ\text{C}$ 

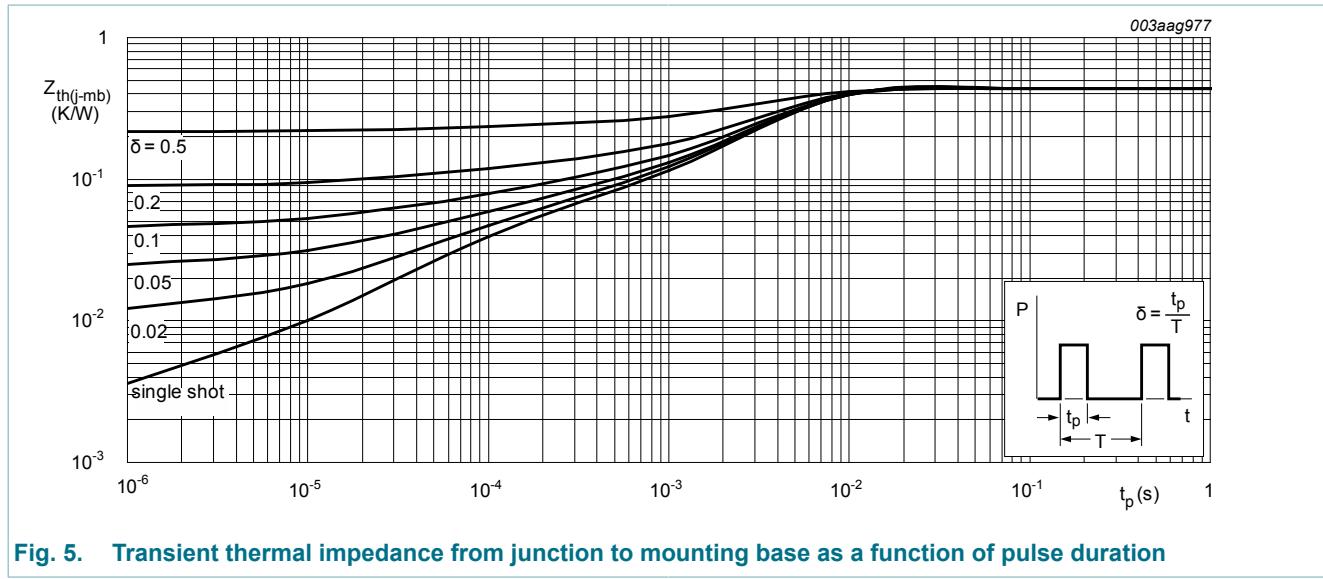
Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^\circ\text{C}$ ;  $I_{DM}$  is a single pulse

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 5</a>		-	0.35	0.43	K/W



## 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Static characteristics</b>							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$		40	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$		36	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C;$ <a href="#">Fig. 10</a> ; <a href="#">Fig. 11</a>		1.05	1.46	1.95	V
		$I_D = 10 mA; V_{DS} = V_{GS}; T_j = 150^\circ C$		0.5	-	-	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C$		-	-	2.25	V
$I_{DSS}$	drain leakage current	$V_{DS} = 40 V; V_{GS} = 0 V; T_j = 25^\circ C$		-	-	1	$\mu A$
		$V_{DS} = 40 V; V_{GS} = 0 V; T_j = 150^\circ C$		-	-	100	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	-	100	nA
		$V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	-	100	nA
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = 4.5 V; I_D = 25 A; T_j = 25^\circ C;$ <a href="#">Fig. 12</a>		-	1.45	1.8	$m\Omega$
		$V_{GS} = 4.5 V; I_D = 25 A; T_j = 150^\circ C;$ <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>		-	-	3.2	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C;$ <a href="#">Fig. 12</a>		-	1.25	1.55	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 150^\circ C;$ <a href="#">Fig. 12</a> ; <a href="#">Fig. 13</a>		-	-	2.7	$m\Omega$
$R_G$	gate resistance	$f = 1 MHz$		-	1.17	2.34	$\Omega$

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Dynamic characteristics</b>							
$Q_{G(\text{tot})}$	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 10 \text{ V};$ <a href="#">Fig. 14</a> ; <a href="#">Fig. 15</a>		-	126	-	nC
		$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 4.5 \text{ V};$ <a href="#">Fig. 14</a>		-	59	-	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$		-	115	-	nC
$Q_{GS}$	gate-source charge	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 4.5 \text{ V};$ <a href="#">Fig. 14</a>		-	17.7	-	nC
$Q_{GS(\text{th})}$	pre-threshold gate-source charge			-	12.5	-	nC
$Q_{GS(\text{th-pl})}$	post-threshold gate-source charge			-	5.2	-	nC
$Q_{GD}$	gate-drain charge			-	15.3	-	nC
$V_{GS(\text{pl})}$	gate-source plateau voltage	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V};$ <a href="#">Fig. 14</a>		-	2.4	-	V
$C_{iss}$	input capacitance	$V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C};$ <a href="#">Fig. 16</a>		-	7790	-	pF
$C_{oss}$	output capacitance			-	1063	-	pF
$C_{rss}$	reverse transfer capacitance			-	409	-	pF
$t_{d(\text{on})}$	turn-on delay time	$V_{DS} = 20 \text{ V}; R_L = 0.8 \Omega; V_{GS} = 4.5 \text{ V};$ $R_{G(\text{ext})} = 4.7 \Omega$		-	41	-	ns
$t_r$	rise time			-	48	-	ns
$t_{d(\text{off})}$	turn-off delay time			-	86	-	ns
$t_f$	fall time			-	42	-	ns
$Q_{oss}$	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C}$		-	38.7	-	nC
<b>Source-drain diode</b>							
$V_{SD}$	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ <a href="#">Fig. 17</a>		-	0.77	1.1	V
$t_{rr}$	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 20 \text{ V};$ <a href="#">Fig. 18</a>		-	44	-	ns
$Q_r$	recovered charge	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 20 \text{ V}$		-	62	-	nC
$t_a$	reverse recovery rise time	$V_{GS} = 0 \text{ V}; I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s};$ $V_{DS} = 20 \text{ V};$ <a href="#">Fig. 18</a>		-	26	-	ns
$t_b$	reverse recovery fall time			-	18	-	ns

## N-channel 40 V 1.55 mΩ logic level MOSFET in LFPAK using NextPower technology

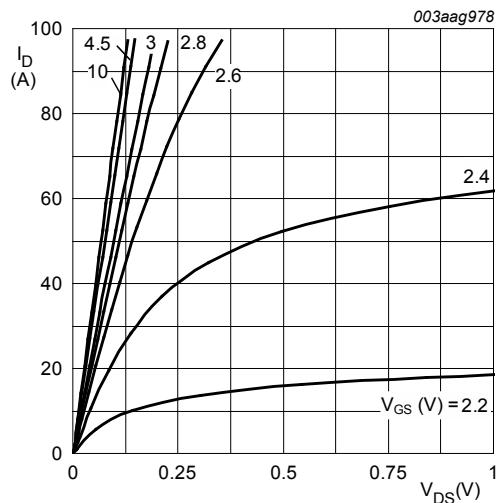


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

$T_j = 25^\circ C$

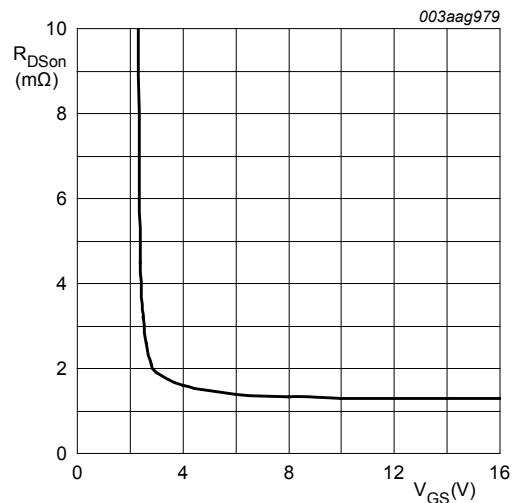


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25^\circ C; I_D = 25A$

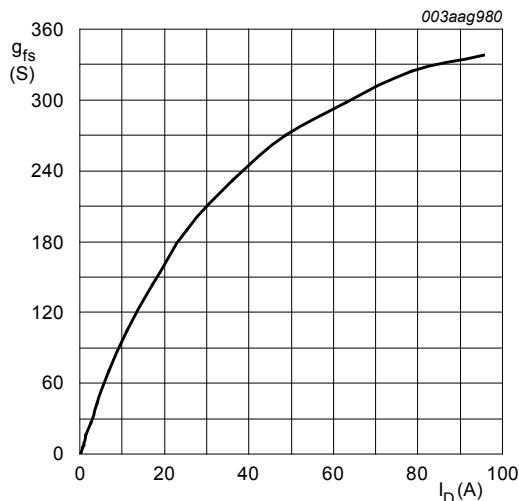


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25^\circ C; V_{DS} = 10V$

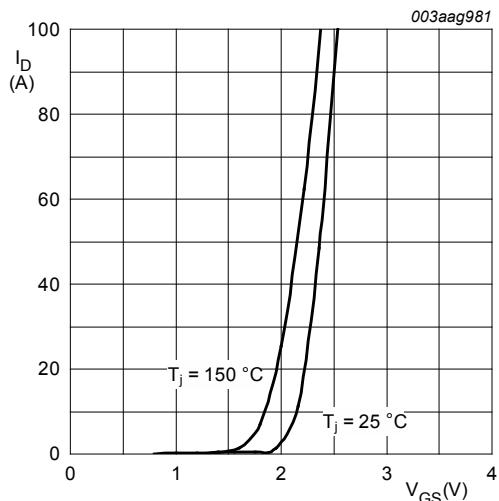


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$V_{DS} = 10V$

## N-channel 40 V 1.55 mΩ logic level MOSFET in LFPAK using NextPower technology

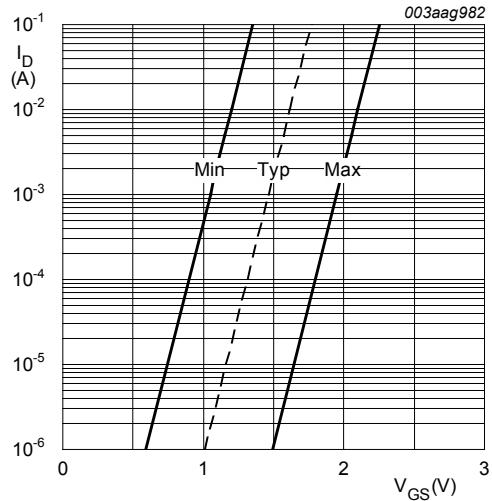


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}$ ;  $V_{DS} = 5\text{V}$

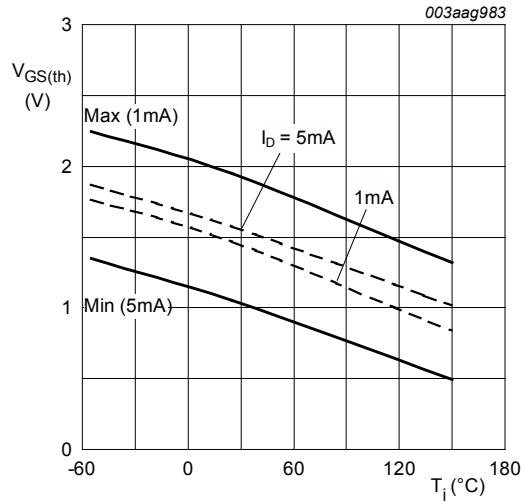


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$V_{DS} = V_{GS}$

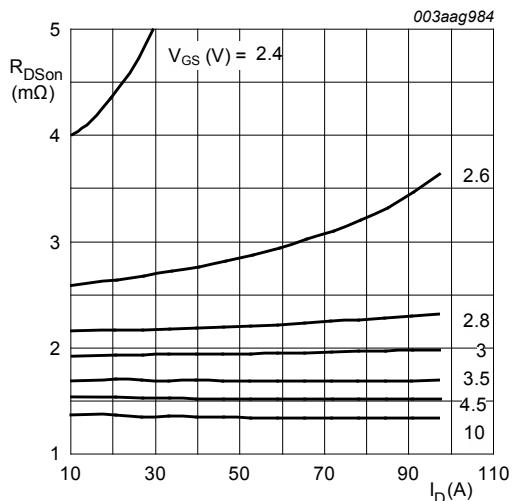


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25^\circ\text{C}$

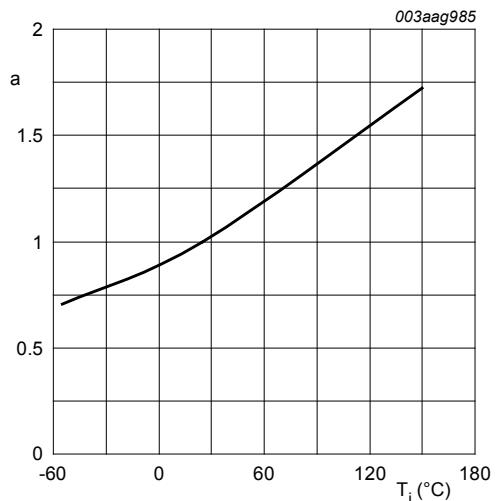
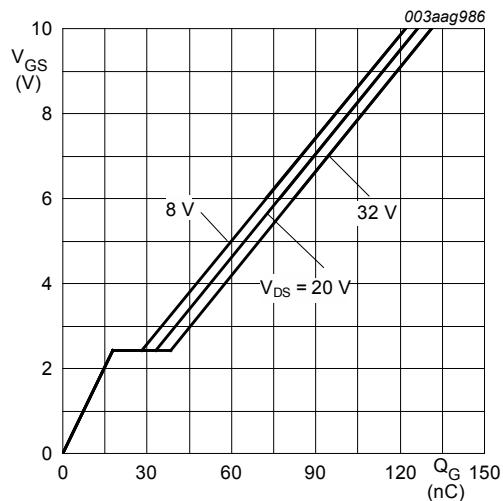


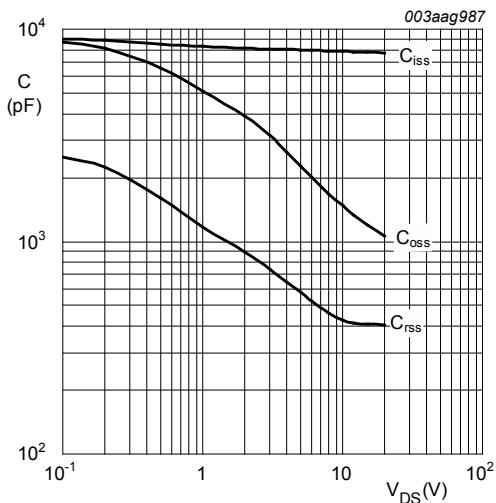
Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)}(25^\circ\text{C})}; V_{GS} \leq 10\text{V}$$

## N-channel 40 V 1.55 mΩ logic level MOSFET in LFPAK using NextPower technology



$T_j = 25^\circ\text{C}$ ;  $I_D = 25\text{A}$



$V_{GS} = 0\text{V}$ ;  $f = 1\text{MHz}$

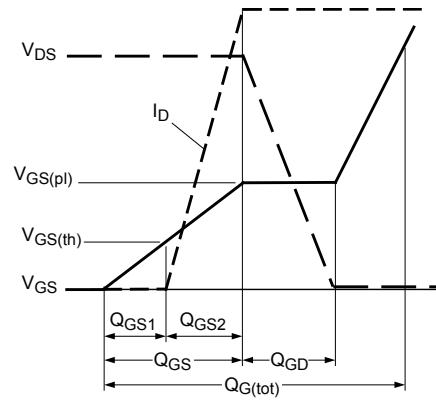
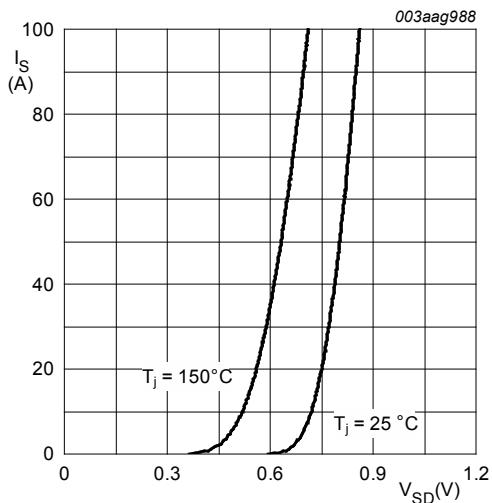


Fig. 15. Gate charge waveform definitions



$V_{GS} = 0\text{V}$

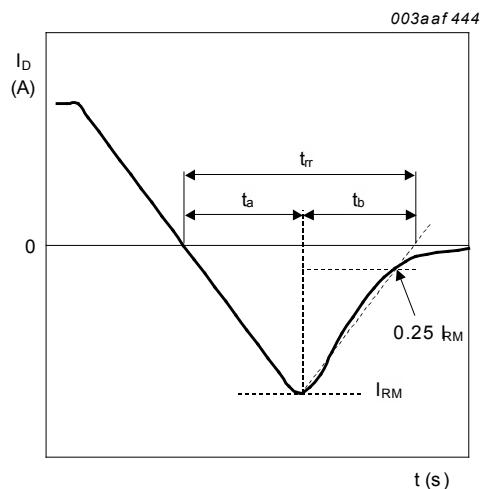


Fig. 18. Reverse recovery timing definition

## 7. Package outline

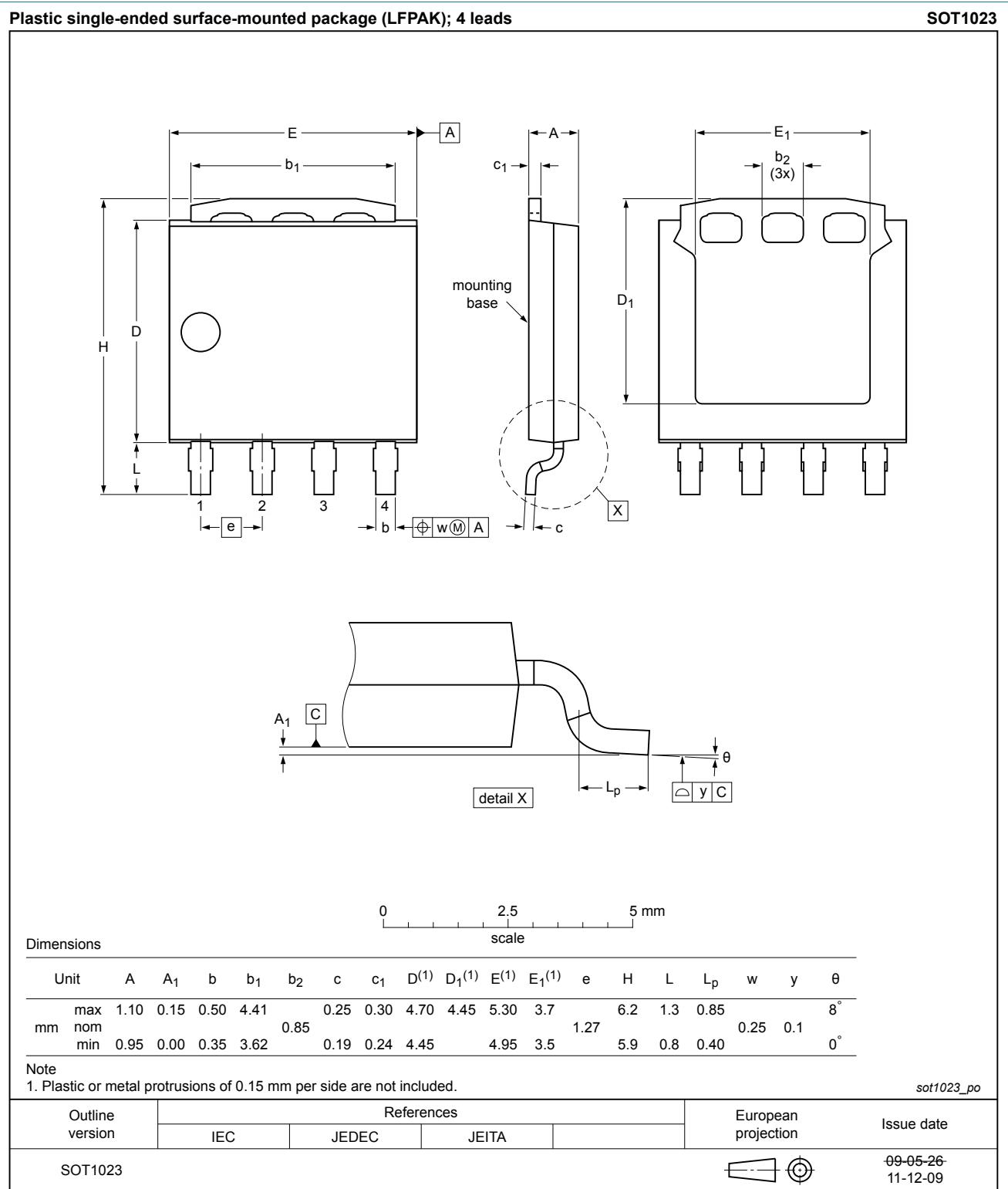


Fig. 19. Package outline LFPAK; Power-SO8 (SOT1023)

## 8. Legal information

### 8.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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## 9. Contents

<b>1</b>	<b>Product profile</b>	<b>1</b>
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
<b>2</b>	<b>Pinning information</b>	<b>2</b>
<b>3</b>	<b>Ordering information</b>	<b>2</b>
<b>4</b>	<b>Limiting values</b>	<b>2</b>
<b>5</b>	<b>Thermal characteristics</b>	<b>4</b>
<b>6</b>	<b>Characteristics</b>	<b>5</b>
<b>7</b>	<b>Package outline</b>	<b>11</b>
<b>8</b>	<b>Legal information</b>	<b>12</b>
8.1	Data sheet status	12
8.2	Definitions	12
8.3	Disclaimers	12
8.4	Trademarks	13

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